NSN 5961-00-192-0314

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-192-0314 **Inclosure Material:** Metal **Overall Length:** 1.550 inches **Overall Height:** Between 0.750 inches and 0.850 inches Overall Width: 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base, rms and 80.0 collector-to-base voltage, instantaneous **Current Rating Per Characteristic:** 50.00 amperes collector current, dc and 15.00 amperes repetitive peak forward current **Power Rating Per Characteristic:** 300.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 1 case and 1 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No